ESD Protection Diodes Silicon Epitaxial Planar

DF2S23P2CTC

1. General

The DF2S23P2CTC is a TVS diode (ESD protection diode) protects semiconductor devices used in mobile device interfaces and other applications to protect against static electricity and noise.

The DF2S23P2CTC has realized high I_{PP} , in order to protect a semiconductor devices from the indirect lightning stroke and the transition voltage (at the time of power activation).

Furthermore, the DF2S23P2CTC is housed in an ultra-compact package (1.6 mm \times 0.8 mm) to meet applications that require a small footprint.

2. Applications

Mobile Equipment

- · Smartphones
- · Tablets
- · Notebook PCs

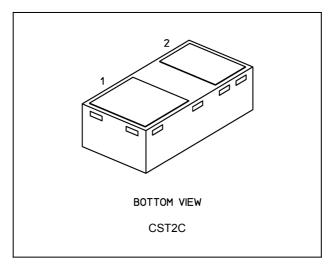
Desktop PCs

Note: This product is designed for protection against electrostatic discharge (ESD) and is not intended for any other purpose, including, but not limited to, voltage regulation.

3. Features

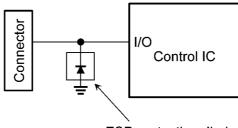
- (1) Suitable for use with a 20 V signal line. (V_{RWM} \leq 21 V)
- (2) Protects devices with its high ESD performance. $(V_{ESD} = \pm 30 \text{ kV} (\text{Contact / Air}) @\text{IEC61000-4-2})$
- (3) Low dynamic resistance protects semiconductor devices from static electricity and noise. $(R_{DYN} = 0.13 \Omega \text{ (typ.)})$
- (4) Snapback characteristics realizing low clamping voltage protects semiconductor devices. $(V_C = 30 \text{ V}@I_{PP} = 14 \text{ A (typ.)})$
- (5) Compact package is suitable for use in high density board layouts such as in mobile devices.
 (1.6 mm × 0.8 mm size (Nickname: CST2C))

4. Packaging



Start of commercial production 2018-04 2018-05-09

5. Example of Circuit Diagram



ESD protection diode

6. Quick Reference Data

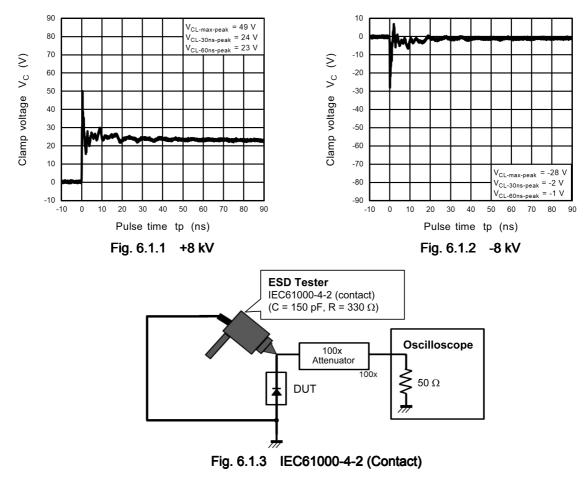
| Characteristics | Symbol | Note | Test Condition | Min | Тур. | Max | Unit |
|--|------------------|----------|----------------|-----|------|-----|------|
| Working peak reverse voltage | V _{RWM} | (Note 1) | _ | _ | _ | 21 | V |
| Dynamic resistance | R _{DYN} | (Note 2) | _ | _ | 0.13 | _ | Ω |
| Electrostatic discharge voltage (IEC61000-4-2) (Contact) | V_{ESD} | (Note 3) | _ | | | 30 | kV |

Note 1: Recommended operating condition.

Note 2: TLP parameters: $Z0 = 50 \Omega$, tp = 100 ns, tr = 300 ps, averaging window: t1 = 30 ns to t2 = 60 ns, extraction of dynamic resistance using least squares fit of TLP characteristics between $I_{PP1} = 16$ A and $I_{PP2} = 30$ A.

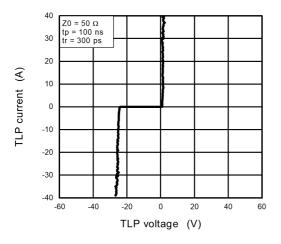
Note 3: Criterion: No damage to devices.

6.1. ESD Clamp Waveform (Note)



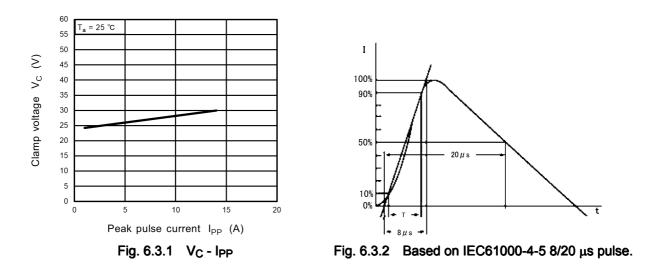
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

6.2. TLP Characteristics (Note)



Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.





Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T_a = 25 °C)

| Characteristics | Symbol | Note | Rating | Unit |
|--|------------------|----------|------------|------|
| Electrostatic discharge voltage (IEC61000-4-2) (Contact) | V _{ESD} | (Note 1) | ±30 | kV |
| Electrostatic discharge voltage (IEC61000-4-2) (Air) | | | ±30 | |
| Peak pulse power (tp = 8/20 μs) | P _{PK} | | 500 | W |
| Peak pulse current (tp = 8/20 μs) | I _{PP} | (Note 2) | 14 | А |
| Junction temperature | Тj | | 150 | °C |
| Storage temperature | T _{stg} | | -55 to 150 | °C |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: According to IEC61000-4-2.

Note 2: According to IEC61000-4-5.

8. Electrical Characteristics (Unless otherwise specified, T_a = 25 °C)

 $\label{eq:second} \begin{array}{l} V_{RWM} \colon \text{Working peak reverse voltage} \\ V_{BR} \colon \text{Reverse breakdown voltage} \\ I_{BR} \colon \text{Reverse breakdown current} \\ I_{R} \colon \text{Reverse current} \\ V_{C} \colon \text{Clamp voltage} \\ I_{PP} \colon \text{Peak pulse current} \\ R_{DYN} \colon \text{Dynamic resistance} \end{array}$

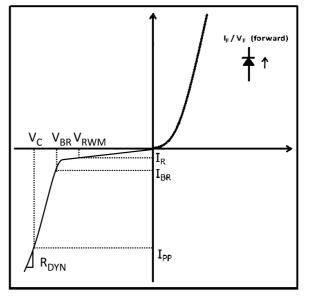


Fig. 8.1 Definitions of Electrical Characteristics

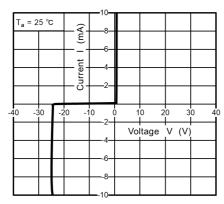
| Characteristics | Symbol | Note | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|------------------|----------|---------------------------------|------|------|------|------|
| Working peak reverse voltage | V_{RWM} | (Note 1) | _ | | | 21 | V |
| Total capacitance | Ct | | V _R = 0 V, f = 1 MHz | _ | 160 | _ | pF |
| Dynamic resistance | R _{DYN} | (Note 2) | — | _ | 0.13 | _ | Ω |
| Reverse breakdown voltage | V _{BR} | | I _{BR} = 1 mA | 21.5 | 24.1 | 25.5 | V |
| Reverse current | I _R | | V _{RWM} = 21 V | _ | _ | 0.1 | μA |
| Clamp voltage | V _C | (Note 3) | I _{PP} = 1 A | | 24.2 | | V |
| | | | I _{PP} = 14 A | _ | 30 | 35.7 | |
| | | (Note 2) | I _{TLP} = 16 A | | 25.5 | | V |
| | | | I _{TLP} = 30 A | | 27.3 | _ | |

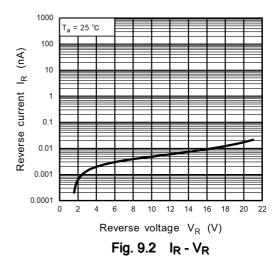
Note 1: Recommended operating condition.

Note 2: TLP parameters: Z0 = 50 Ω , tp = 100 ns, tr = 300 ps, averaging window: t1 = 30 ns to t2 = 60 ns, extraction of dynamic resistance using least squares fit of TLP characteristics between I_{PP1} = 16 A and I_{PP2} = 30 A.

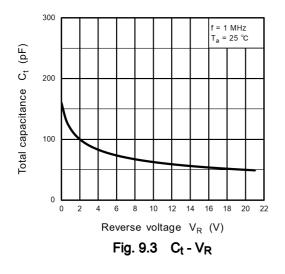
Note 3: Based on IEC61000-4-5 8/20 µs pulse.

9. Characteristics Curves (Note)





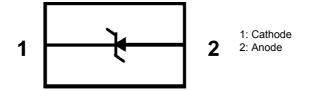




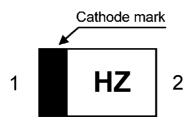
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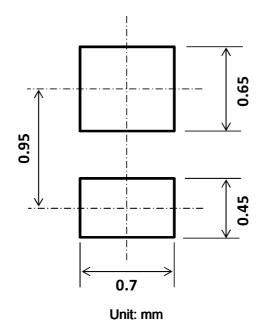
10. Internal Circuit



11. Marking (Top view)



12. Land Pattern Dimensions (for reference only)

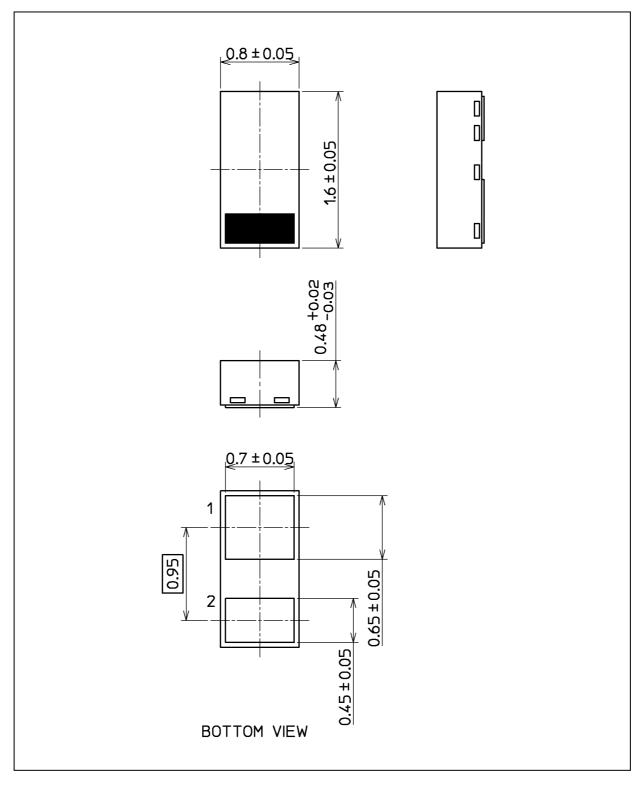




DF2S23P2CTC

Package Dimensions

Unit: mm



Weight: 1.5 mg (typ.)

Package Name(s)

Nickname: CST2C

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